TSFF5510



Vishay Semiconductors

High Speed Infrared Emitting Diode, 870 nm, GaAlAs Double Hetero



DESCRIPTION

TSFF5510 is an infrared, 870 nm emitting diode in GaAlAs double hetero (DH) technology with high radiant power and high speed, molded in a clear, untinted plastic package.

FEATURES

- · Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- · Leads with stand-off
- Peak wavelength: λ_p = 870 nm
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity: $\phi = \pm 38^{\circ}$
- Low forward voltage
- Suitable for high pulse current operation
- High modulation bandwidth: f_c = 24 MHz
- · Good spectral matching with Si photodetectors
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Note

APPLICATIONS

- Infrared video data transmission between camcorder and TV set
- Free air data transmission systems with high data transmission rates

PRODUCT SUMMARY					
COMPONENT	l _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)	
TSFF5510	32	± 38	870	15	

Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATI	ATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
TSFF5510	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		

Note

• MOQ: minimum order quantity

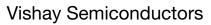
ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		I _F	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	1	А	
Power dissipation		Pv	180	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 85	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	$t \le 5$ s, 2 mm from case	T _{sd}	260	°C	
Thermal resistance junction/ambient	J-STD-051, leads 7 mm soldered on PCB	R _{thJA}	230	K/W	

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Document Number: 81835



^{**} Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902





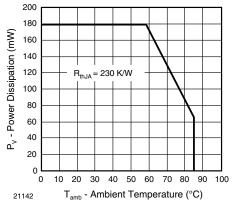


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

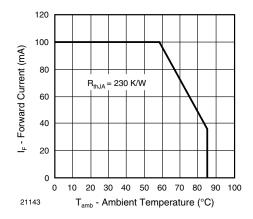


Fig. 1 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F	1.3	1.45	1.7	V
Forward voltage	I _F = 450 mA, t _p = 100 μs	V _F	1.5	1.75	2.1	V
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V _F		2.1		V
Temperature coefficient of V _F	I _F = 1 mA	TK _{VF}		- 1.8		mV/K
Reverse current	V _R = 5 V	I _R			10	μA
Junction capacitance	V _R = 0 V, f = 1 MHz, E = 0	Cj		110		pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l _e	16	32	48	mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фе		55		mW
Temperature coefficient of ϕ_{e}	I _F = 100 mA	TKφe		- 0.35		%/K
Angle of half intensity		φ		± 38		deg
Peak wavelength	I _F = 100 mA	λρ		870		nm
Spectral bandwidth	I _F = 100 mA	Δλ		55		nm
Temperature coefficient of λ_p	I _F = 100 mA	ΤΚλρ		0.25		nm/K
Rise time	I _F = 100 mA	t _r		15		ns
Fall time	I _F = 100 mA	t _f		15		ns
Cut-off frequency	I_{DC} = 70 mA, I_{AC} = 30 mA pp	f _c		24		MHz



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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

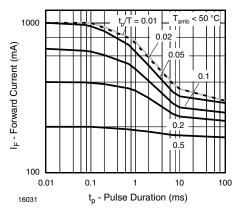


Fig. 2 - Pulse Forward Current vs. Pulse Duration

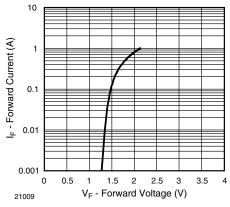


Fig. 3 - Forward Current vs. Forward Voltage

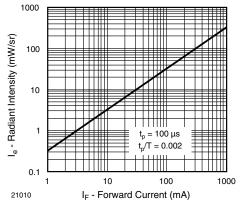


Fig. 4 - Radiant Intensity vs. Forward Current

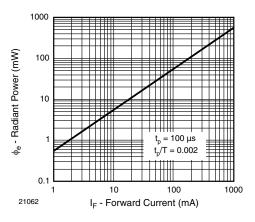


Fig. 5 - Radiant Power vs. Forward Current

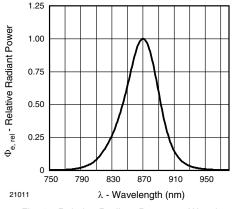
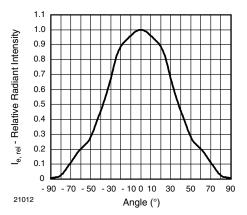


Fig. 6 - Relative Radiant Power vs. Wavelength





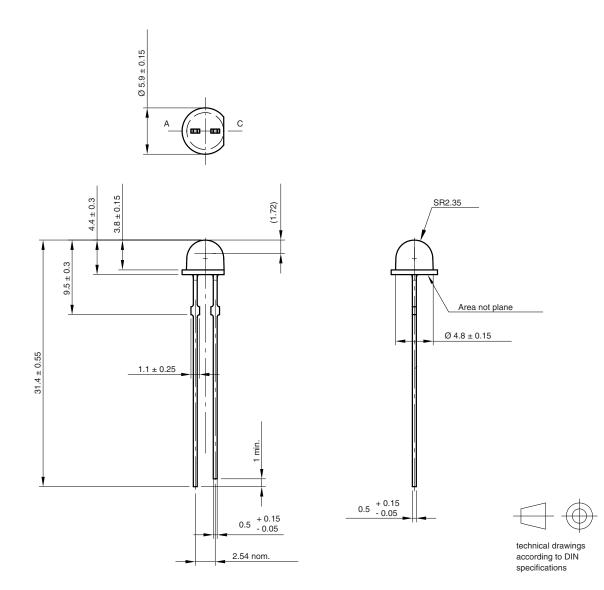
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PACKAGE DIMENSIONS in millimeters

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